

**EXHIBIT D.06**  
**U.S. Patent No. 6,853,142**

References cited herein:

- U.S. Pat. No. 6,853,142 (“142 Patent”)
- U.S. Pat. No. 6,413,382 (“Wang”)
- A. A. Kudryavtsev, *et al*, Ionization relaxation in a plasma produced by a pulsed inert-gas discharge, Sov. Phys. Tech. Phys. 28(1), January 1983 (“Kudryavtsev”)

‘142 Claims 21, 22, 23, 25-30, 31, 33-39, 41, and 43	Wang in view of Kudryavtsev
<p>[21pre.] An apparatus for generating a strongly-ionized plasma, the apparatus comprising:</p>	<p>The combination of Wang and Kudryavstev discloses an apparatus for generating a strongly-ionized plasma.</p> <p>Wang at Fig. 1</p> <p>Wang at 7:19-25 (“Preferably, the peak power <math>P_P</math> is at least 10 times the background power <math>P_B</math>, more preferably at least 100 times, and most preferably 1000 times to achieve the greatest effect of the invention. A background power <math>P_B</math> of 1kW will typically be sufficient to support a plasma with the torpedo magnetron and a 200 mm wafer although with little if any actual sputter deposition.”)</p> <p>Wang at 7:28-30 (“ the application of the high peak power <math>P_P</math> instead quickly causes the already existing plasma to spread and increases the density of the plasma”)</p> <p>Wang at 7:31-39 (“In one mode of operating the reactor, during the background period, little or no target sputtering is expected. The SIP reactor is advantageous for a low-power, low-pressure background period since the small rotating SIP magnetron can maintain a plasma at lower power and lower pressure than can a larger stationary magnetron. However, it is possible to combine highly ionized sputtering during the pulses with significant neutral sputtering during the background period.”)</p>
<p>[21a.] an anode;</p>	<p>The combination of Wang and Kudryavstev discloses an anode.</p> <p>‘142 Patent at 2:21-22 (“FIG. 1 illustrates a cross-sectional view of a known plasma generating apparatus</p>

**EXHIBIT D.06**  
**U.S. Patent No. 6,853,142**

<p style="text-align: center;">'142 Claims 21, 22, 23, 25-30, 31, 33-39, 41, and 43</p>	<p style="text-align: center;">Wang in view of Kudryavtsev</p>
	<p>100...”)</p> <p>'142 Patent at 2:45-46 (“An anode 130 is positioned in the vacuum chamber 104 proximate to the cathode 114.”)</p> <p>Wang at Fig. 1</p> <p>Wang at 3:66-4:1 (A grounded shield 24 protects the chamber walls from sputter deposition and also acts as a grounded anode for the cathode of the negatively biased target 14.”). (emphasis added)</p>
<p>[21b.] a cathode that is positioned adjacent to the anode and forming a gap there between;</p>	<p>The combination of Wang and Kudryavstev discloses a cathode that is positioned adjacent to the anode and forming a gap there between.</p> <p>'142 Patent at 2:21-22 (“FIG. 1 illustrates a cross-sectional view of a known plasma generating apparatus 100...”)</p> <p>'142 Patent at 2:45-46 (“An anode 130 is positioned in the vacuum chamber 104 proximate to the cathode 114.”)</p> <p>Wang at Fig. 1</p> <p>Wang at 3:66-4:1 (A grounded shield 24 protects the chamber walls from sputter deposition and also acts as a grounded anode for the <i>cathode of the negatively biased target 14.</i>”). (emphasis added)</p> <p>Wang at 3:63-65 (“A pedestal electrode 18 supports a wafer 20 to be sputter coated in planer opposition to the target 14 across a processing region 22.”)</p>
<p>[21c.] an ionization source that generates a weakly-ionized plasma proximate to the cathode, the weakly-ionized plasma reducing the probability of developing an electrical breakdown condition between the anode and the cathode;</p>	<p>The combination of Wang and Kudryavstev discloses an ionization source that generates a weakly-ionized plasma proximate to the cathode, the weakly-ionized plasma reducing the probability of developing an electrical breakdown condition between the anode and the cathode.</p> <p>Wang at Fig. 7</p>

**EXHIBIT D.06**  
**U.S. Patent No. 6,853,142**

‘142 Claims 21, 22, 23, 25-30, 31, 33-39, 41, and 43	Wang in view of Kudryavtsev
and	<p>Wang at 4:5-6 (“A sputter working gas such as argon is supplied from a gas source 32....”)</p> <p>Wang at 4:20-21 (“... a reactive gas, for example nitrogen is supplied to the processing space 22....”)</p> <p>Wang at 7:17-31 (“The background power level <math>P_B</math> is chosen to exceed the minimum power necessary to support a plasma... [T]he application of the high peak power <math>P_P</math> quickly causes the already existing plasma to spread and increases the density of the plasma.”)</p> <p>Wang at 7:19-25 (“Preferably, the peak power <math>P_P</math> is at least 10 times the background power <math>P_B</math> ... and most preferably 1000 times to achieve the greatest effect of the invention. A background power <math>P_B</math> of 1 kW [causes] little if any actual sputter deposition.”)</p> <p>Wang at 4:23-31 (Ex. 1005) (“...<u>thus creating a region 42 of a high-density plasma (HDP).</u>...”)</p> <p>Wang at 7:3-49 (“Plasma ignition, particularly in plasma sputter reactors, has a tendency to generate particles during the initial arcing, which may dislodge large particles from the target or chamber... The initial plasma ignition needs be performed only once and at much lower power levels so that particulates produced by arcing are much reduced.”)</p> <p>Wang at 7:25-28 (“As a result, once the plasma has been ignited at the beginning of sputtering prior to the illustrated waveform, no more plasma ignition occurs.”).</p> <p>Wang at 7:58-61 (“... DC power supply 100 is connected to the target 14 ... and supplies an essentially constant negative voltage to the target 14 corresponding to the background power <math>P_B</math>.”)</p> <p>Wang at 7:22-23 (“A background power <math>P_B</math> of 1 kW will typically be sufficient to support a plasma...”)</p>
[21d.] a power supply that produces an electric field across the gap, the	The combination of Wang and Kudryavstev discloses a power supply that produces an electric field across the

**EXHIBIT D.06**  
**U.S. Patent No. 6,853,142**

<b>'142 Claims 21, 22, 23, 25-30, 31, 33-39, 41, and 43</b>	<b>Wang in view of Kudryavtsev</b>
<p>electric field generating excited atoms in the weakly-ionized plasma and generating secondary electrons from the cathode, the secondary electrons ionizing the excited atoms, thereby creating the strongly-ionized plasma.</p>	<p>gap, the electric field generating excited atoms in the weakly-ionized plasma and generating secondary electrons from the cathode, the secondary electrons ionizing the excited atoms, thereby creating the strongly-ionized plasma.</p> <p>'142 Patent at 1:41-43 ("Magnetron sputtering systems use magnetic fields that are shaped to trap and to concentrate secondary electrons, which are produced by ion bombardment of the target surface.")</p> <p>'142 Patent at 1:37-40 ("The plasma is replenished by electron-ion pairs formed by the collision of neutral molecules with secondary electrons generated at the target surface.")</p> <p>Wang at Fig. 7</p> <p>Wang at 7:61-62 ("The pulsed DC power supply 80 produces a train of negative voltage pulses.")</p> <p>Wang at 7:19-25 ("Preferably, the peak power level <math>P_p</math> is at least 10 times the background power level <math>P_B</math>, ... most preferably 1000 times to achieve the greatest effects of the invention. A background power <math>P_B</math> of 1 kW will typically be sufficient...")</p> <p>Wang at 7:36-39 ("However, it is possible to combine highly ionized sputtering during the pulses with significant neutral sputtering during the background period.")</p> <p>Kudryavtsev at Figs. 1, 6</p> <p>Kudryavtsev at 34, right col, ¶ 4 ("[s]ince the effects studied in this work are characteristic of ionization whenever a field is suddenly applied to a weakly ionized gas, they must be allowed for when studying emission mechanisms in pulsed gas lasers, gas breakdown, laser sparks, etc.")</p> <p>Kudryavtsev at 31, right col, ¶ 6 ("For nearly stationary <math>n_2</math> [excited atom density] values ... there is an explosive</p>

**EXHIBIT D.06**  
**U.S. Patent No. 6,853,142**

<b>'142 Claims 21, 22, 23, 25-30, 31, 33-39, 41, and 43</b>	<b>Wang in view of Kudryavtsev</b>
	<p>increase in <math>n_e</math> [plasma density]. The subsequent increase in <math>n_e</math> then reaches its maximum value, equal to the rate of excitation [equation omitted], which is several orders of magnitude greater than the ionization rate during the initial stage.”)</p> <p>Kudryavtsev at Abstract (“in a pulsed inert-gas discharge plasma at moderate pressures... [i]t is shown that the electron density increases explosively in time due to accumulation of atoms in the lowest excited states.”)</p> <p>Kudryavtsev at Equation 1</p> <p>Kudryavtsev at 30, right col, last ¶ (“<math>n_2</math>, and <math>n_e</math> are the atomic densities in the ... first excited states and the electron density, respectively ... <math>\beta_{2e}</math> [is] the rate coefficient[.]...”)</p> <p><i>See</i> evidence cited in [21pre] of claim 21.</p> <p>If one of ordinary skill, applying Wang’s power levels did not experience Kudryavtsev’s “explosive increase” in plasma density, it would have been obvious to adjust the operating parameters, e.g., increase the pulse length and/or pressure, so as to trigger Kudryavtsev’s fast stage of ionization. One of ordinary skill would have been motivated to use Kudryavtsev’s fast stage of ionization in Wang so as to increase plasma density and thereby increase the sputtering rate. Further, use of Kudryavtsev’s fast stage in Wang would have been a combination of old elements that yielded predictable results of increasing plasma density and multi-step ionization.</p> <p>Kudryavtsev states, “[s]ince the effects studied in this work are characteristic of ionization whenever a field is suddenly applied to a weakly ionized gas, they must be allowed for when studying emission mechanisms in pulsed gas lasers, gas breakdown, laser sparks, etc.” Kudryavtsev at 34, right col, ¶ 4. Because Wang applies voltage pulses that “suddenly generate an electric field,” one of ordinary skill reading Wang would have been motivated to consider Kudryavtsev and to use</p>

# Explore Litigation Insights

Docket Alarm provides insights to develop a more informed litigation strategy and the peace of mind of knowing you're on top of things.

## Real-Time Litigation Alerts



Keep your litigation team up-to-date with **real-time alerts** and advanced team management tools built for the enterprise, all while greatly reducing PACER spend.

Our comprehensive service means we can handle Federal, State, and Administrative courts across the country.

## Advanced Docket Research



With over 230 million records, Docket Alarm's cloud-native docket research platform finds what other services can't. Coverage includes Federal, State, plus PTAB, TTAB, ITC and NLRB decisions, all in one place.

Identify arguments that have been successful in the past with full text, pinpoint searching. Link to case law cited within any court document via Fastcase.

## Analytics At Your Fingertips



Learn what happened the last time a particular judge, opposing counsel or company faced cases similar to yours.

Advanced out-of-the-box PTAB and TTAB analytics are always at your fingertips.

## API

Docket Alarm offers a powerful API (application programming interface) to developers that want to integrate case filings into their apps.

## LAW FIRMS

Build custom dashboards for your attorneys and clients with live data direct from the court.

Automate many repetitive legal tasks like conflict checks, document management, and marketing.

## FINANCIAL INSTITUTIONS

Litigation and bankruptcy checks for companies and debtors.

## E-DISCOVERY AND LEGAL VENDORS

Sync your system to PACER to automate legal marketing.